



**THE DATASHEET OF
TFI343V-500-24_14MM**





TET ESTEL AS
ESTONIA

April
2016

Series
TFI343V-500

High Frequency Inverter grade
Capsule Thyristor
Type TFI343V-500

Low switching losses

Low reverse recovery charge

Distributed amplified gate for high di/dt

Maximum mean on-state current	I_{TAV}	500 A
Maximum repetitive peak off-state and reverse voltage	U_{DRM} U_{RRM}	2000 ÷ 2400 V
Turn-off time	t_q	32; 40 μs
U_{DRM}, U_{RRM}, V	2000	2200
		2400
Voltage code	20	22
		24
$T_{vj}, ^\circ C$	- 60 ÷ 125	

MAXIMUM ALLOWABLE RATINGS

Symbols and parameters		Units	TFI343V-500	Conditions
I_{TAV}	Mean on-state current	A	500 727	$T_c=83^\circ C$, $T_c=55^\circ C$, 180° half-sine wave, 50 Hz
I_{TRMS}	RMS on-state current	A	785	$T_c=83^\circ C$
I_{TSM}	Surge on-state current	kA	10,0 11,0	$T_{vj}=125^\circ C$ $T_{vj}=25^\circ C$ tp=10 ms
I^2t	Limiting load integral	kA^2s	500 605	$T_{vj}=125^\circ C$ $T_{vj}=25^\circ C$ $U_R=0$
U_{DRM}, U_{RRM}	Repetitive peak off-state and reverse voltage	V	2000÷2400	$T_j \min \leq T_{vj} \leq T_{jM}$ 180° half-sine wave, 50 Hz Gate open
U_{DSM}, U_{RSM}	Non-repetitive peak off-state and reverse voltage	V	2100÷2500	$T_j \min \leq T_{vj} \leq T_{jM}$ 180° half-sine wave tp=10 ms, Single pulse Gate open
(di _T /dt) crit	Critical rate of rise of on-state current : non - repetitive repetitive	A/ μ s	2000 1250	$T_{vj}=125^\circ C$; $U_D=0,67 U_{DRM}$, Gate pulse : 10V,5 Ω , 1 μ s rise time, 10 μ s
U_{RGM}	Peak reverse gate voltage	V	5	$T_j \min \leq T_{vj} \leq T_{jM}$
T_{stg}	Storage temperature	$^\circ C$	-60÷80	
T_{vj}	Junction temperature	$^\circ C$	-60÷125	

CHARACTERISTICS

U_{TM}	Peak on-state voltage	V	2,6	$T_{vj}=25^\circ C$, $I_{TM}=3,14 I_{TAV}$
$U_{T(To)}$	Threshold voltage	V	1,6	$T_{vj}=125^\circ C$
R_T	On-state slope resistance	m Ω	0,69	1,57 $I_{TAV} < I_T < 4,71 I_{TAV}$
I_{DRM} I_{RRM}	Repetitive peak off-state and reverse current	mA	70; 70 0,7; 0,7	$T_{vj}=125^\circ C$, $U_D = U_{DRM}$; $U_R = U_{RRM}$ $T_{vj}=25^\circ C$, $U_D = U_{DRM}$; $U_R = U_{RRM}$

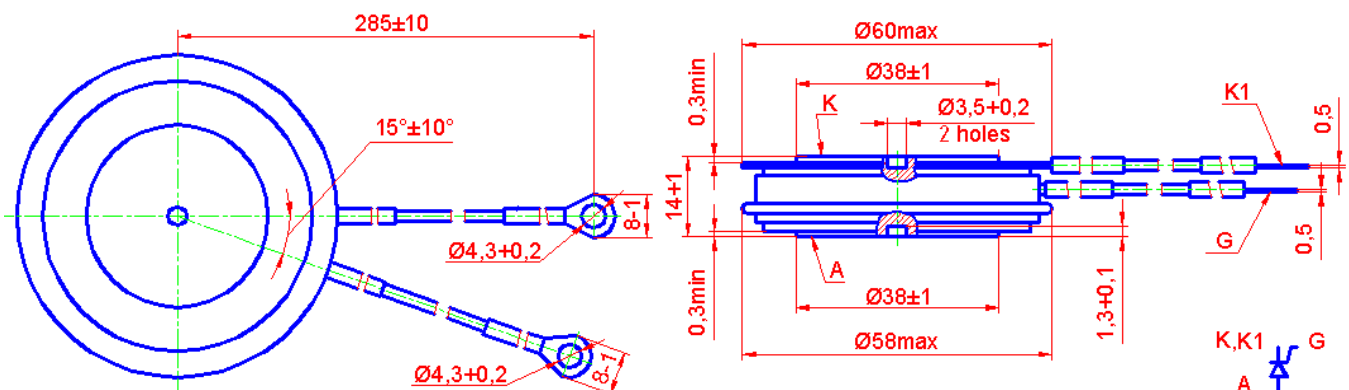
CHARACTERISTICS

Symbols and parameters		Units	TFI343V-500	Conditions
I_L	Latching current	A	7	$T_{vj}=25^{\circ}\text{C}, U_D=12\text{V}$ Gate pulse : 10V, 5 μs , 1 μs rise time, 10 μs
I_H	Holding current	A	0,5	$T_{vj}=25^{\circ}\text{C}, U_D=12\text{V}$, Gate open
U_{GT}	Gate trigger direct voltage	V	2,5 5,0	$T_{vj}=25^{\circ}\text{C}$, $T_{vj}=-60^{\circ}\text{C}$
I_{GT}	Gate trigger direct current	A	0,3 0,8	$T_{vj}=25^{\circ}\text{C}$, $T_{vj}=-60^{\circ}\text{C}$
U_{GD}	Gate non-trigger direct voltage	V	0,25	$T_{vj}=125^{\circ}\text{C}$, $U_D = 0,67 U_{DRM}$ Direct gate current
I_{GD}	Gate non-trigger direct current	mA	10	
t_{gd}	Delay time	μs	1,6	$T_{vj}=25^{\circ}\text{C}, U_D=500\text{V}$ $I_{TM} = 500 \text{ A}$
t_{gt}	Turn-on time	μs	3,2	Gate pulse : 10V, 5 μs , 1 μs rise time, 10 μs
t_q	Turn-off time	μs	32÷40 40÷50	$T_{vj}=125^{\circ}\text{C}$, $I_{TM} = 500 \text{ A}$ $di_R/dt = 10 \text{ A}/\mu\text{s}$, $U_R=100\text{V}$ $U_D = 0,67 U_{DRM}$ $du_D/dt=50 \text{ V}/\mu\text{s}$ $du_D/dt=200 \text{ V}/\mu\text{s}$
Q_{rr}	Recovered charge	μC	400	
t_{rr}	Reverse recovery time	μs	5,5	$T_{vj}=125^{\circ}\text{C}$, $I_{TM} = 500 \text{ A}$
I_{rrm}	Peak reverse recovery current	A	145	$di_R/dt = 50 \text{ A}/\mu\text{s}$, $U_R=100\text{V}$
$(du_D/dt)_{crit}$	Critical rate of rise of off-state voltage	$\text{V}/\mu\text{s}$	500 1000	$T_{vj}=125^{\circ}\text{C}$, $U_D = 0,67 U_{DRM}$ Gate open
R_{thjc}	Thermal resistance junction to case	$^{\circ}\text{C}/\text{W}$	0,034	Direct current, double side cooled

ORDERING

	TFI	343V	500	22	7	4	3	
	1	2	3	4	5	6	7	

- Fast thyristor with interdigitated gate structure.
- Design version.
- Mean on-state current, A.
- Voltage code (22=2200 V).
- Critical rate of rise of off-state voltage ($6 \geq 500 \text{ V}/\mu\text{s}$, $7 \geq 1000 \text{ V}/\mu\text{s}$).
- Group of turn-off time ($du_D/dt=50 \text{ V}/\mu\text{s}$, $3 \leq 40 \mu\text{s}$, $4 \leq 32 \mu\text{s}$).
- Group of turn-on time ($2 \leq 3,2 \mu\text{s}$).



Mounting force : 13÷19 kN

Weight : 210 grams

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